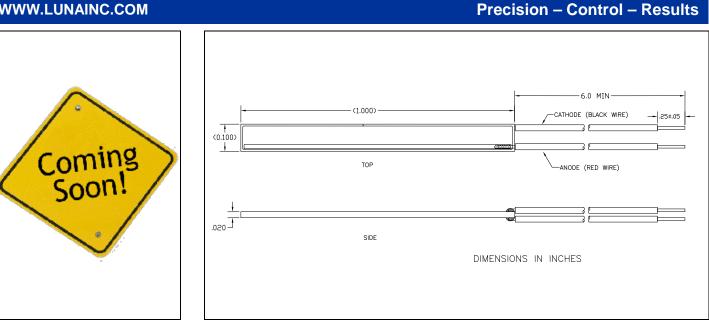




Solderable Planar Photodiode

PRELIMINARY

WWW.LUNAINC.COM



DESCRIPTION

The SLSD-71N400 is a solderable planar photodiode featuring low cost, high reliability, and linear short circuit current over a wide range of illumination. These devices are widely used for light sensing and power generation because of their stability and high efficiency. They are particularly suited to power conversion applications due to their low internal impedance, relatively high shunt impedance, and stability. The photodiodes have a protective coating that protects them from humidity effects.

RELIABILITY

This Luna high-reliability device is in principle able to meet military test requirements (Mil-STD-750, Mil-STD-883) after proper screening and group test.

Contact Luna for recommendations on specific test conditions and procedures.

FEATURES

- Visible to IR spectral irradiance range •
- High reliability •
- Oxide passivation
- Linear short circuit current •
- Low capacitance, high speed •
- Si surface protected with the thin film •
- coating

APPLICATIONS

- Light sensing
- Power generation

SYMBOL	MIN		MAX	UNITS	
Operating Temperature	-40	to	+105	°C	Non-condensing
Storage Temperature	-40	to	+105	°C	-
Soldering Temperature	-	to	+240	°C	-
Wavelength Range	400	То	1100	nm	-

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.

ABSOLUTE MAXIMUM RATINGS

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SLSD-71N400

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OPTO-ELECTRICAL PARAMETERS

Precision – Control – Results

T _a =	23°C UNI	ESS NOTED	OTHERWISE
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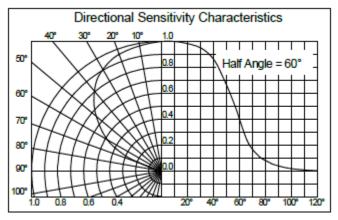
PARAMETER	TEST CONDITIONS	MIN	ТҮР 2.3	MAX -	UNITS	
Short Circuit Current	$V_{R} = 0V, Ee = 25 mW/cm^{2**}$	1.4			mA	
Open Circuit Voltage	Ee = 25mW/cm ² **	-	0.40	-	V	
Dark Current	V _R = 5V, Ee=0, T=25°C	-	-	5.0	μΑ	
Junction Capacitance	$V_{R=}0V$, Ee = 0, f=1MHz	-	1.5	-	nF	
Spectral Sensitivity	λ -940nm, Flood illumination*	-	0.55	-	A/W	
Breakdown Voltage	I _R = 100μA	20	-	-	V	
Maximum Sensitivity Wavelength	-	-	930	-	nm	
Acceptance Half Angle	(off center line)	-	60	-	deg	

* Minimum 50% of active area illuminated

**Light source @ 2854°K

TYPICAL PERFORMANCE

DIRECTIONAL SENSIVITY



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